查询"2SA1832\_03"**他实施**A Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1832

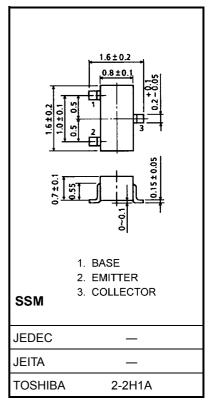
#### Audio Frequency General Purpose Amplifier Applications

Unit: mm

- $\bullet~$  High voltage and high current: VCEO = -50 V, IC = -150 mA (max)
- Excellent hFE linearity: hFE (IC = -0.1 mA)/ hFE (IC = -2 mA) = 0.95 (typ.)
- High h<sub>FE</sub>:  $h_{FE} = 70 \sim 400$
- Complementary to 2SC4738
- Small package

## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-150	mA
Base current	ΙΒ	-30	mA
Collector power dissipation	P <sub>C</sub>	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Weight: 2.4 mg (typ.)

#### **Electrical Characteristics (Ta = 25°C)**

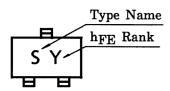
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$		_	-0.1	μΑ
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$	70	_	400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		4	7	pF

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Note: hFE classification O (O): 70~140, Y (Y): 120~240, GR (G): 200~400

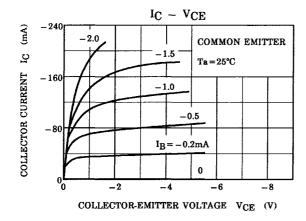
( ) marking symbol

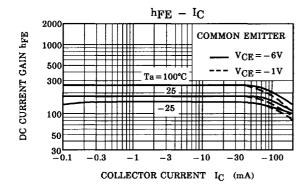
#### Marking

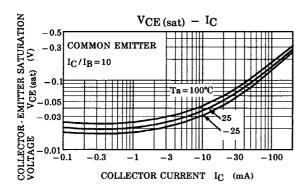


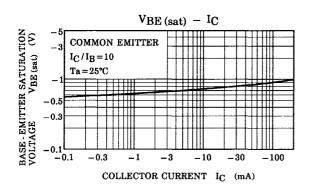
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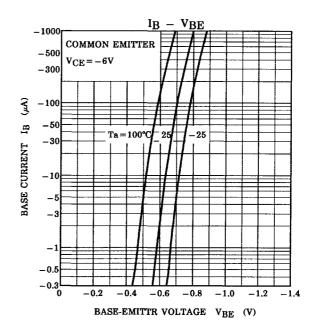
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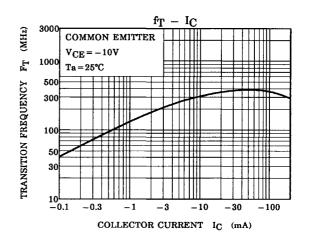


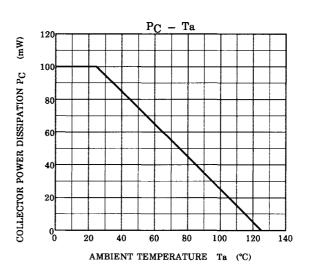












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